

## 1.3GHz I<sup>2</sup>C BUS 4-Address Synthesiser

Supersedes version in April 1994 Consumer IC Handbook, HB3120 - 2.0

DS3031 - 5.0 January 1997

The SP5502 is a single-chip frequency synthesiser designed for TV tuning systems. Control data is entered in the standard I $^2$ C BUS format. The SP5502 has four programmable I $^2$ C BUS addresses, which allows two or more synthesisers to be used in a system.

The device is available in two variants: the SP5502F in 14-lead miniature plastic package (MP14) and the SP5502S in 16-lead miniature plastic package (MP16). See Features below for functional differences between the devices.

#### **FEATURES**

- Complete 1:3GHz Single Chip System
- Programmable via the I<sup>2</sup>C BUS
- Low Power Consumption (240mW Typ.)
- Low Radiation
- Phase Lock Detector
- Varactor Drive Amp Disable
- 5×20mA Controllable Outputs (SP5502S)
- 3×20mA Controllable Outputs (SP5502F)
- Variable I<sup>2</sup>C BUS Address for Multi-Tuner Applications
- ESD Protection \*

<sup>\*</sup> Normal ESD handling precautions should be observed.

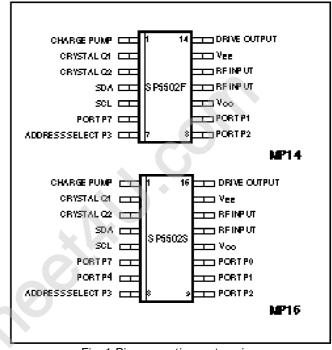


Fig. 1 Pin connections - top view

#### **APPLICATIONS**

- Cable Tuning Systems
- VCRs

#### ORDERING INFORMATION

SP5502F KG MPAS (14-lead miniature plastic package) SP5502S KG MPAS (16-lead miniature plastic package)

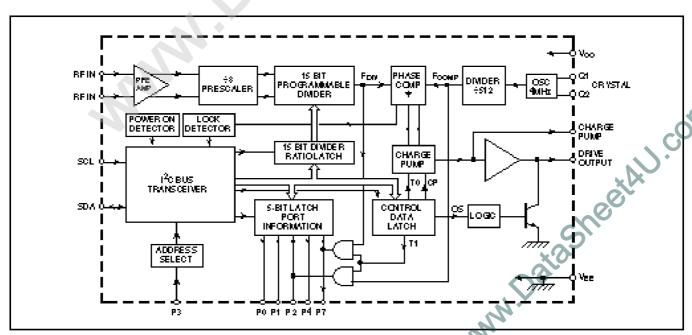


Fig. 2 Block diagram of SP5502S. (Ports P0 and P4 not present on SP5502F)

#### SP5502

#### **ELECTRICAL CHARACTERISTICS**

 $T_{AMB} = -10^{\circ}$ C to  $+80^{\circ}$ C,  $V_{CC} = +4.5$ V to +5.5V. All pin references are to the SP5502S (MP16 package). These Characteristics are guaranteed by either production test or design. They apply within the specified ambient temperature and supply voltage ranges unless otherwise stated. Reference frequency 4MHz unless otherwise stated.

Characteristic	Pin	Value			Units	O		
Characteristic	Pin	Min.	Тур.	Max.	Units	Conditions		
Supply current	12		48	60	mA	V <sub>CC</sub> = 5V		
Prescaler input voltage	13,14	12·5		300	mVrms	80MHz to 1GHz		
Prescaler input voltage		30		300	mVrms	1·3GHz, see Fig. 5		
Prescaler input impedance	13,14		50		Ω			
Prescaler input capacitance			2		рF			
SDA, SCL								
Input high voltage	4,5	3		V <sub>cc</sub>	V			
Input low voltage	4,5	0		1.5	V			
Input high current	4,5			10	μA	Input voltage = V <sub>CC</sub>		
Input low current	4,5			-10	μA	Input voltage = 0V		
Leakage current	4,5			10	μA	When $V_{CC} = 0V$		
SDA								
Output voltage	4			0.4	V	Sink current = 3mA		
Charge pump current low	1		±50		μA	Byte 4, bit 2 = 0, pin 1 = 2V		
Charge pump current high	1		±170		μA	Byte 4, bit 2 = 1, pin 1 = 2V		
Charge pump output leakage current	1			±5	nA	Byte 4, bit 4 = 1, pin 1 = 2V		
Charge pump drive output current	16	500				V pin 16 = 0·7V		
Charge pump amplifier gain			6400					
Recommended crystal series resistance		10		200	Ω	Parallel resonant crystal (note 2)		
Crystal oscillator drive level			40		mV p-p			
Crystal oscillator negative resistance	2	750			Ω			
Output Ports								
Sink current	6,7,9-11	20			mA	$V_{OUT} = 0.7V$ (see note 1)		
Leakage current	6,7,9-11			10	μΑ	V <sub>OUT</sub> = 13·2V		
Input Port								
P3 input current high	8			1	mA	V pin 8 = V <sub>CC</sub>		
P3 input current low	8			-0∙5	mA	V pin 8 = 0V		

#### **NOTES**

# FUNCTIONAL DESCRIPTION (Except where otherwise indicated, 'SP5502' refers to both variants)

The SP5502 is programmed from an I<sup>2</sup>C BUS. Data and Clock are fed in on the SDA and SCL lines respectively as defined by the I2C Bus format. The synthesiser can either accept new data (write mode) or send data (read mode). The Tables in Fig. 3 illustrate the format of the data. The device can be programmed to respond to several addresses, which enables the use of more than one synthesiser in an I<sup>2</sup>C Bus system. Table 3 shows how the address is selected by applying a voltage to P3. The address input is shown in Fig. 6. The LSB of the address Byte (R/W) sets the device into read mode if it is high and write mode if it is low. When the SP5502 receives a correct address Byte it pulls the SDA line low during the acknowledge period and during following acknowledge periods after further data Bytes are programmed. When the SP5502 is programmed into the read mode the controlling device accepting the data must pull down the SDA line during the following acknowledge period to read another status Byte.

#### WRITE MODE (FREQUENCY SYNTHESIS)

When the device is in the write mode Bytes 2+3 select the synthesised frequency while Bytes 4+5 select the output port states and charge pump information.

Once the correct address is received and acknowledged, the first Bit of the next Byte determines whether that Byte is interpreted as Byte 2 or 4, a logic 0 for frequency information and a logic 1 for charge pump and output port information. Additional data Bytes can be entered without the need to readdress the device until an I<sup>2</sup>C stop condition is recognised. This allows a smooth frequency sweep for fine tuning or AFC purposes.

If the transmission of data is stopped mid-byte (i.e., by another device on the bus) then the previously programmed byte is maintained.

Frequency data from Bytes 2 and 3 is stored in a 15-bit shift register and is used to control the division ratio of the 15-bit programmable divider which is preceded by a divide-by-8 prescaler and amplifier to give excellent sensitivity at the local oscillator input; see Fig 5. The input impedance is shown in Fig

<sup>1.</sup> Source impedance between all output ports and ground is approximately  $5\Omega$ . This should be taken into account when calculating output port saturation voltages.

<sup>2.</sup> The maximum resistance quoted refers to all conditions, including start-up.

The programmed frequency can be calculated by multiplying the programmed division ratio by 8 times the comparison frequency  $F_{\text{COMP}}$ .

When frequency data is entered, the phase comparator, via the charge pump and varactor drive amplifier, adjusts the local oscillator control voltage until the output of the programmable divider is frequency and phase locked to the comparison frequency.

The reference frequency may be generated by an external source capacitively coupled into pin 2 or provided by an on-chip 4MHz crystal controlled oscillator.

Note that the comparison frequency is 7·8125kHz when a 4MHz reference is used.

Bit 2 of Byte 4 of the programming data (CP) controls the current in the charge pump circuit, a logic 1 for  $\pm 170\mu A$  and a logic 0 for  $\pm 50\mu A$ , allowing compensation for the variable tuning slope of the tuner and also to enable fast channel changes over the full band. Bit 4 of Byte 4 (T0) disables the

charge pump if set to a logic 1. Bit 8 of Byte 4 (OS) switches the charge pump drive amplifier's output off when it is set to a logic 1. Bit 3 of Byte 4 (T1) selects a test mode where the phase comparator inputs are available on P2 and P7, a logic 1 connects  $F_{COMP}$  to P2 and  $F_{DIV}$  to P7.

Byte 5 programs the output ports P0-P2, P4 and P7 on the SP5502S (P1, P2 and P7 only on SP5502F), a logic 0 for a high impedance output, logic 1 for low impedance (on).

#### **READ MODE**

When the device is in the read mode the status data read from the device on the SDA line takes the form shown in Table 2. Bit 1 (POR) is the power supply to the device has dropped below a nominal 3V and the programmed information lost (e.g., when the device is initially turned on). The POR is set to 0 when the read sequence is terminated by a stop command. The outputs are all set to high impedance when the device is initially powered up. Bit 2 (FL) indicates whether the device is phase locked, a logic 1 is present if the device is locked and a logic 0 if the device is unlocked.

MSB						LSB					
Address	1	1	0	0	0	MA1	MA0	0	Α	Byte 1	
Programmable divider	0	2 <sup>14</sup>	2 <sup>13</sup>	<b>2</b> <sup>12</sup>	2 <sup>11</sup>	2 <sup>10</sup>	2 <sup>9</sup>	2 <sup>8</sup>	Α	Byte 2	
Programmable divider	<b>2</b> <sup>7</sup>	2 <sup>6</sup>	<b>2</b> <sup>5</sup>	2 <sup>4</sup>	2 <sup>3</sup>	<b>2</b> <sup>2</sup>	2 <sup>1</sup>	2º	Α	Byte 3	
Charge pump and test bits	1	СР	T1	ТО	1	1	1	os	Α	Byte 4	
I/O port control bits	P7	Х	Х	P4*	Х	P2	P1	P0*	Α	Byte 5	

Table 1 Write data format (MSB transmitted first)

Address	1	1	0	0	0	MA1	MA0	1	Α	Byte 1
Status byte	POR	FL	N	Ν	N	N	N	Ν	Α	Byte 2

Table 2 Read data format

MA1	MAO	Voltage input to P3
0	0	0V to 0·1V <sub>CC</sub>
0	1	Open circuit
1	0	0.4V <sub>CC</sub> to 0.6V <sub>CC</sub> †
1	1	0.9V <sub>CC</sub> to V <sub>CC</sub>

Table 3 Address selection

A : Acknowledge bit

MA1, MA0 : Variable address bits (see Table 3)

CP : Charge Pump current select

T1 : Test mode selection
T0 : Charge pump disable

OS : Varactor drive Output disable Switch
P7, P4\*, P2, P1, P0\* : Control output port states
POR : Power On Reset indicator
FL : Phase lock detect flag

X : Don't care
N : Not valid

#### **NOTES**

† Programmed by connecting a 15k $\Omega$  resistor between Address Select Port P3 and V<sub>CC</sub>.

\* Don't care condition on SP5502F.

Fig. 3 Data formats

### SP5502

#### **APPLICATION**

A typical application is shown in Fig. 4. All input/output interface circuits are shown in Fig. 6.

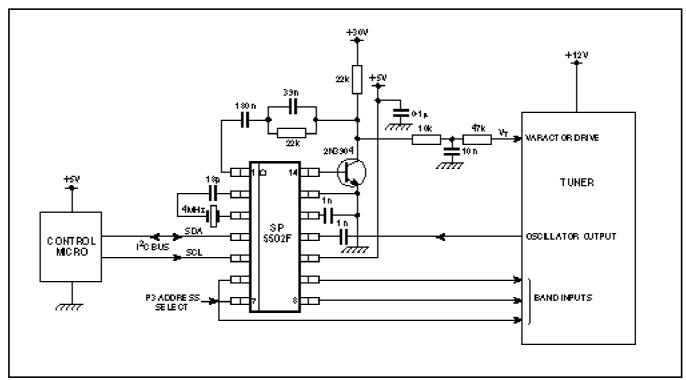


Fig. 4 Typical application

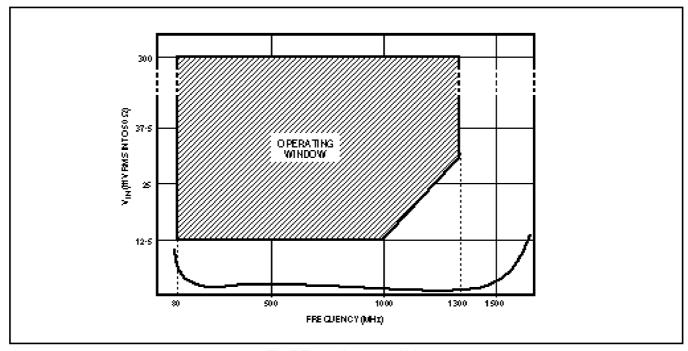


Fig. 5 Typical input sensitivity

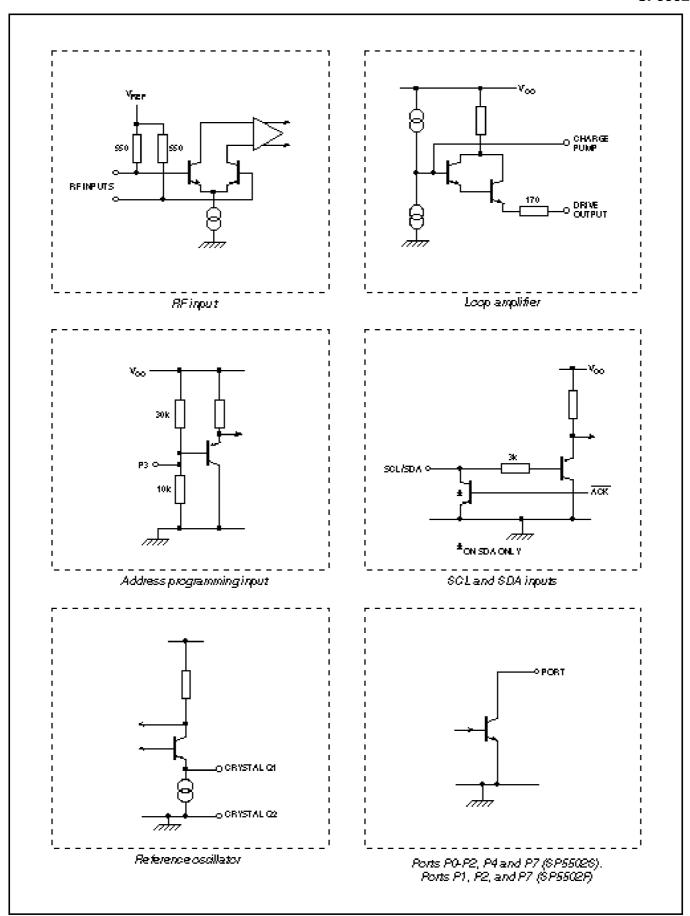


Fig. 6 SP5502 input/output interface circuits

### SP5502

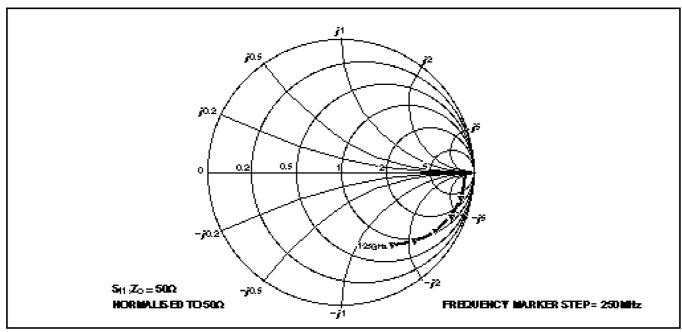


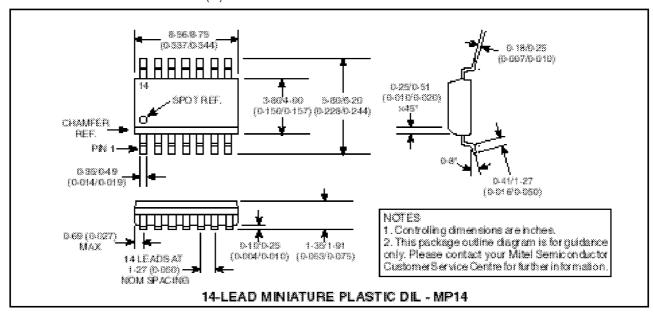
Fig. 7 Typical input impedance

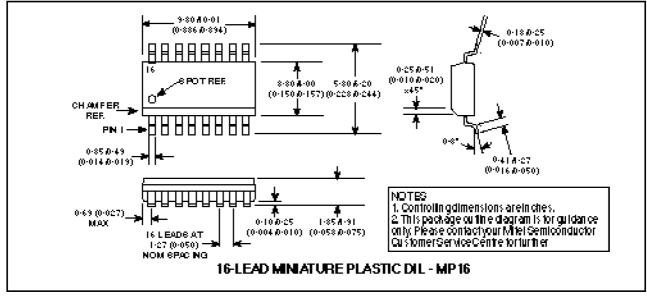
ABSOLUTE MAXIMUM RATINGS All voltages are referred to  $V_{\text{EE}} = 0V$ 

Parameter	Р	in	Va	lue	Units	Conditions	
i arameter	SP5502S	SP5502F	Min.	Max.	Oilles	Conditions	
Supply voltage	12	10	-0.3	7	V		
RF input voltage	13,14	11,12		2.5	V p-p		
Port voltage	6,7, 9-11 6,7, 9-11 8	6,8, 9 6,8, 9 7	-0·3 -0·3 -0·3	14 6 V <sub>CC</sub> +0·3	V V V	Port in off state Port in on state	
Total port output current	6,7, 9-11	6,8, 9		50	mA		
RF input DC offset	13,14	11,12	-0.3	V <sub>CC</sub> +0·3	V		
Charge pump DC offset	1	1	-0.3	V <sub>CC</sub> +0·3	V		
Drive output DC offset	16	14	-0.3	V <sub>CC</sub> +0·3	V		
Crystal oscillator DC offset	2	2	-0.3	V <sub>CC</sub> +0·3	V		
SDA, SCL input voltage	4,5	4,5	-0.3	V <sub>CC</sub> +0⋅3	V	With V <sub>CC</sub> applied	
			-0.3	5∙5	V	V <sub>CC</sub> not applied	
Storage temperature			-55	+150	∘c		
Junction temperature				+150	∘c		
MP16 thermal resistance, chip-to-ambient MP16 thermal resistance, chip-to-case				111 41	°C/W		
MP14 thermal resistance, chip-to-ambient MP14 thermal resistance, chip-to-case				123 45	°C/W		
Power consumption at 5·5V				363	mW		

#### **PACKAGE DETAILS**

Dimensions are shown thus: mm (in).







Purchase of Mitel Semiconductor I<sup>2</sup>C components conveys a licence under the Philips I<sup>2</sup>C Patent rights to use these components in an I<sup>2</sup>C System, provided that the system conforms to the I<sup>2</sup>C Standard Specification as defined by Philips.

## HEADQUARTERS OPERATIONS MITEL SEMICONDUCTOR

Cheney Manor, Swindon, Wiltshire SN2 2QW, United Kingdom.

Tel: (01793) 518000 Fax: (01793) 518411

#### MITEL SEMICONDUCTOR

Scotts Valley, California 95066-4922 United States of America. Tel (408) 438 2900 Fax: (408) 438 5576/6231 Internet: http://www.gpsemi.com

**CUSTOMER SERVICE CENTRES** 

- FRANCE & BENELUX Les Ulis Cedex Tel: (1) 69 18 90 00 Fax: (1) 64 46 06 07
- GERMANY Munich Tel: (089) 419508-20 Fax : (089) 419508-55
- ITALY Milan Tel: (02) 6607151 Fax: (02) 66040993
- JAPAN Tokyo Tel: (03) 5276-5501 Fax: (03) 5276-5510
- KOREA Seoul Tel: (2) 5668141 Fax: (2) 5697933
- NORTH AMERICA Scotts Valley, USA Tel: (408) 438 2900 Fax: (408) 438 5576/6231
- SOUTH EAST ASIA Singapore Tel:(65) 3827708 Fax: (65) 3828872
- **SWEDEN** Stockholm Tel: 46 8 702 97 70 Fax: 46 8 640 47 36
- TAIWAN, ROC Taipei Tel: 886 2 25461260 Fax: 886 2 27190260
- UK, EIRÉ, DENMARK, FINLAND & NORWAY
   Swindon Tel: (01793) 726666 Fax: (01793) 518582

These are supported by Agents and Distributors in major countries world-wide.

© Mitel Corporation 1998 Publication No. DS3031 Issue No. 5.0 January 1997
TECHNICAL DOCUMENTATION – NOT FOR RESALE. PRINTED IN UNITED KINGDOM

This publication is issued to provide information only which (unless agreed by the Company in writing) may not be used, applied or reproduced for any purpose nor form part of any order or contract nor to be regarded as a representation relating to the products or services concerned. No warranty or guarantee express or implied is made regarding the capability, performance or suitability of any product or service. The Company reserves the right to alter without prior notice the specification, design or prior eof any product or service. Information concerning possible methods of use is provided as a guide only and does not constitute any guarantee that such methods of use will be satisfactory in a specific piece of equipment. It is the user's responsibility to fully determine the performance and suitability of any equipment using such information and to ensure that any publication or data used is up to date and has not been superseded. These products are not suitable for use in any medical products whose failure to perform may result in significant injury or death to the user. All products and materials are sold and services provided subject to the Company's conditions of sale, which are available or request.